

PIE310 · PID310D

A modulative emitting diode and a modulative detecting photo IC with connector has been put together in a package. The use of the emitter and detector as a pair enables it to work as a penetrative type photo-sensor of approximately 100cm (can be practically used as a reflective type sensor). Can be used as a paper sensor due to easy equipping and its high anti-dust factor.

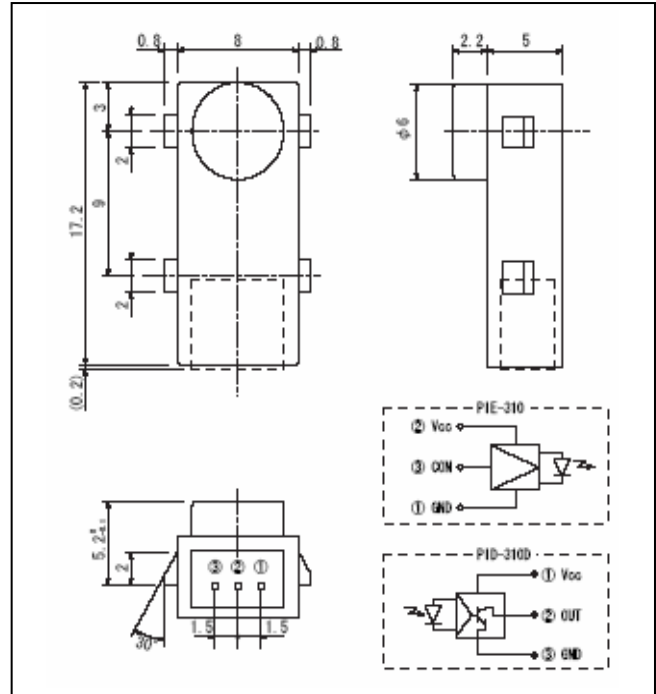
PIE310 : Modulated emitting diode
 PID310D : Modulated Photo IC

Features

- Anti-visible rays due to visible ray cut resin for detector type
- Connector type(JAE IL-Y type)
- Dust proof

Dimensions

(Unit : mm)



Applications

- ATM
- Auto stampers
- Card readers / writers
- Optical switches

Absolute Maximum Ratings

[Ta = 25°C]

Description		Symbol	Ratings	Unit
Emitter	Supply voltage	V_{CC}	7	v
	Supply voltage	V_{CC}	13.2	v
Detector	Low level output current	I_{OL}	30	mA
	Power dissipation	P_D	100	mW
Operating temp. *1		$T_{opr.}$	-10~+60	°C
Storage temp. *1		$T_{stg.}$	-20~+80	°C

*1. No icebound or dew

Electro-Optical Characteristics

[Vcc= 5V, Ta = 25°C]

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Emitter	Operating supply voltage	V_{CC}	4.75	-	5.25	v
	Current consumption	I_{CC}	-	15	30	mA
	Peak wavelength	λ_p	-	830	-	nm
	Half angle	$\Delta\theta$	-	±5	-	deg.
Detector	Operating supply voltage	V_{CC}	4.75	-	5.25	v
	Low level output voltage	V_{OL}	-	-	0.4	v
	High level output voltage	V_{OH}	4.0	-	-	v
	Current consumption	I_{CC}	-	5	10	mA
	Half angle	$\Delta\theta$	-	±5	-	deg.
Combination	Detecting distance	L	100	200	850	cm
	Hysteresis	I_{FHL}/I_{FLH}	-	0.9	-	-
	L→H propagation time	t_{PLH}	-	-	0.5	ms
	H→L propagation time	t_{PHL}	-	-	0.5	ms